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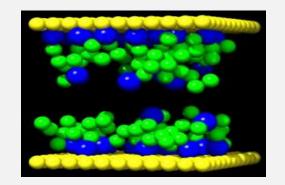
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The NACK Network, established at the Pennsylvania State College of Engineering, and funded in part by a grant from the National Science Foundation (DUE 1205105).





Today's Presenter

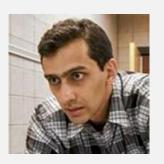


Christina Arisio, Ivy Tech Community College of Indiana

Since 2013, I have been an assistant professor of Nanotechnology at Ivy Tech Community College of Indiana, South Bend campus. I am currently working to finish a Ph.D. in Chemistry with Dr. Marya Lieberman. My research focuses on the functionalization of Si and GaN semiconductors and III-V (nitride) high electron mobility transistors with silane self-assembled monolayers for biosensor applications. My undergraduate work was done at SUNY Stony Brook (B.S. in Chemistry) with Dr. Stanislaus S. Wong. This research involved the synthesis and characterization of strontium titanate nanocubes. Portions of my undergraduate work were carried out at Brookhaven National Laboratory.



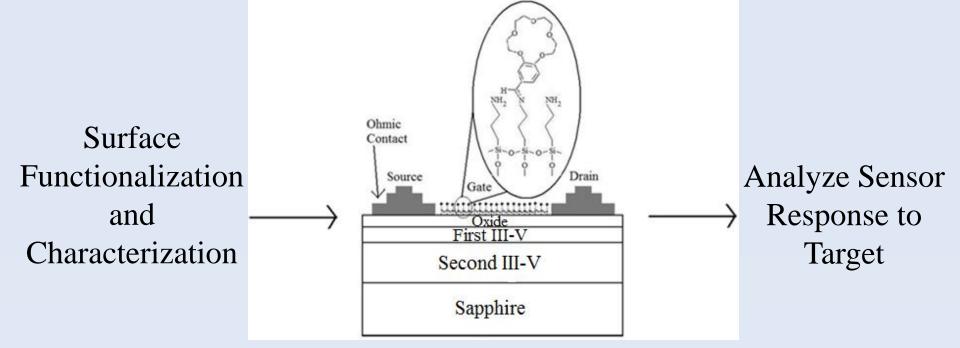
Host: Roxanna Montoya MATEC



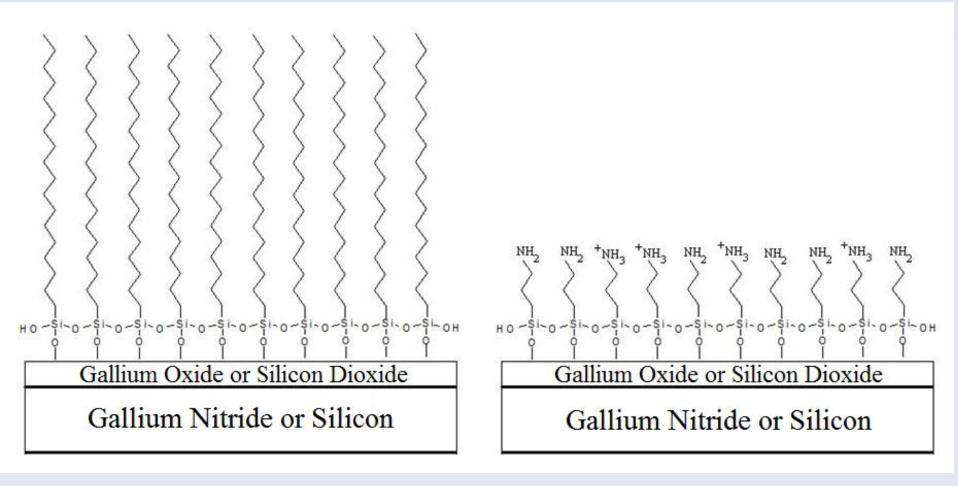
Moderator: Sam Agdasi Assistant Professor and Chair, Nanotechnology, Ivy Tech Community College

Self-Assembled Monolayers Silane SAM's for Bioapplications

Christina Arisio
Ivy Tech Community College



Siloxane SAM's on GaN and on Si

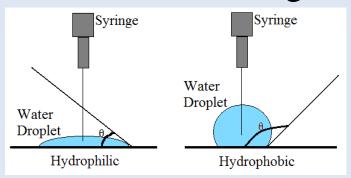


OTS - Octadecyltrichlorosilane

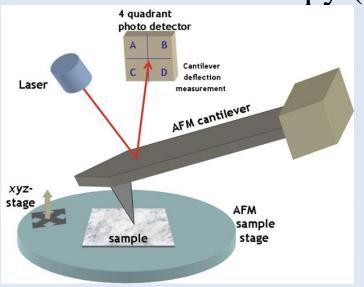
APTES -Aminopropyltriethoxysilane

Surface Analysis Techniques

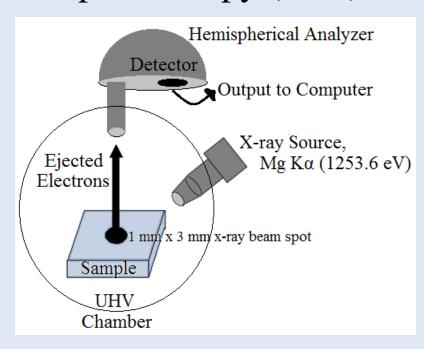
Water Contact Angle



Atomic Force Microscopy (AFM)



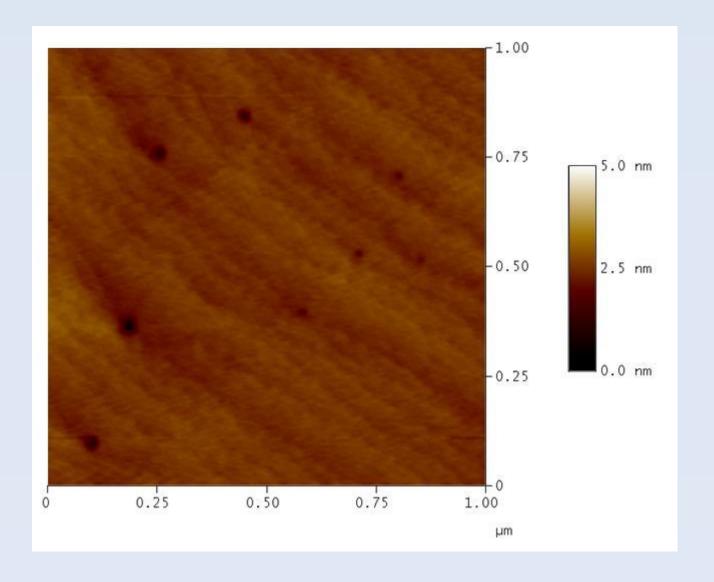
X-Ray Photoelectron Spectroscopy (XPS)



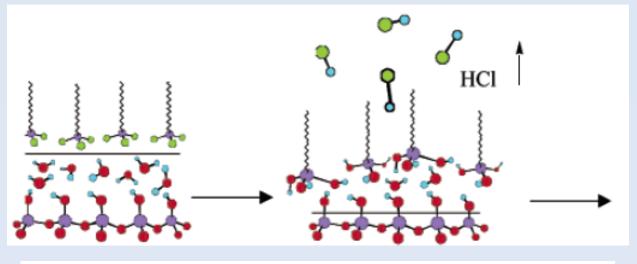
Mølhave; Opensource Handbook of Nanoscience and Nanotechnology, AFM (2006)

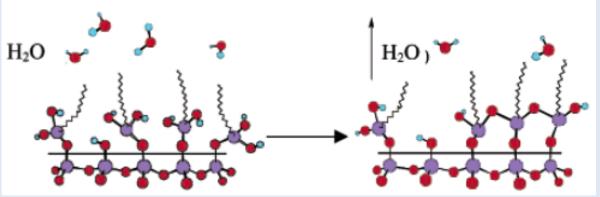
Unfunctionalized Clean GaN Surface

Surface preparation/ treatment is critical!

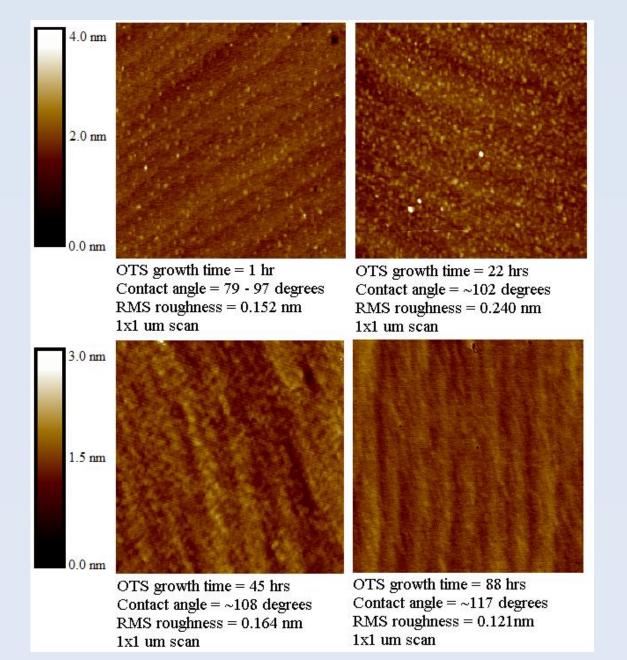


Monolayer Growth Deposition in Solution

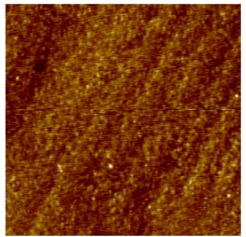




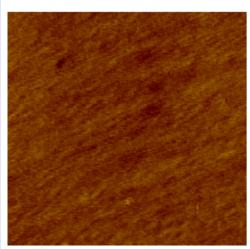
OTS Functionalized GaN Surface



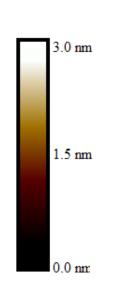
APTES Functionalized GaN Surface



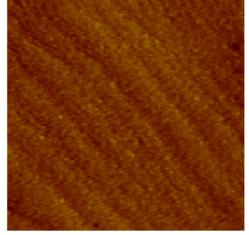
APTES growth time = 15 min Contact angle = low 60's RMS roughness = 0.255 nm 1x1 um scan



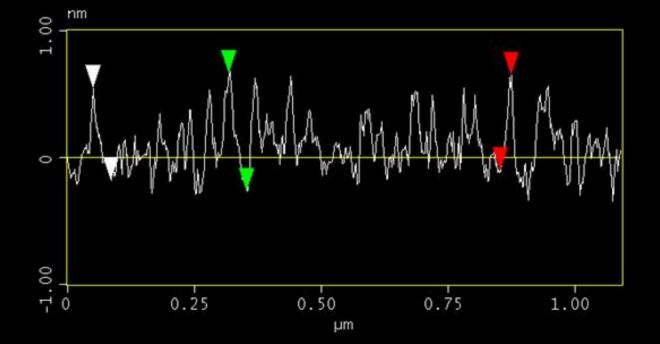
APTES growth time = 45 min Contact angle = low 70's RMS roughness = 0.182 nm 1x1 um scan

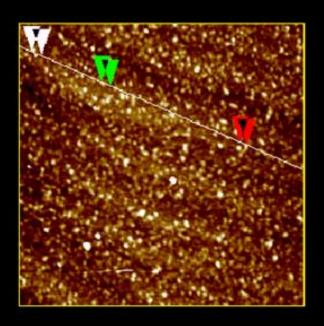


APTES growth time = 25 min Contact angle = low 60's RMS roughness = 0.229 nm 1x1 um scan



APTES growth time = 1hr Contact angle = low 80's RMS roughness = 0.186 nm 1x1 um scan



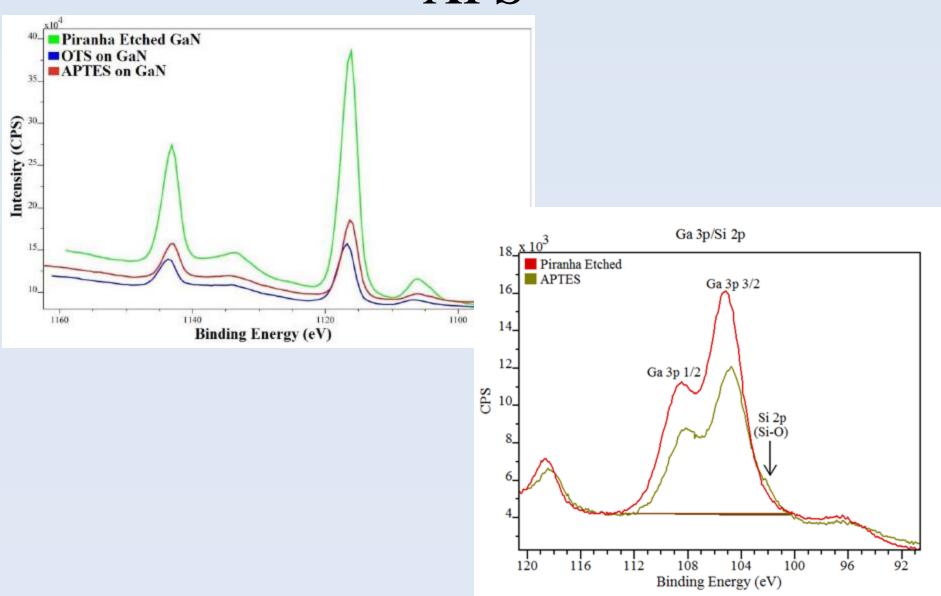


Vertical Distance 0.722 nm

Vertical Distance 0.936 nm

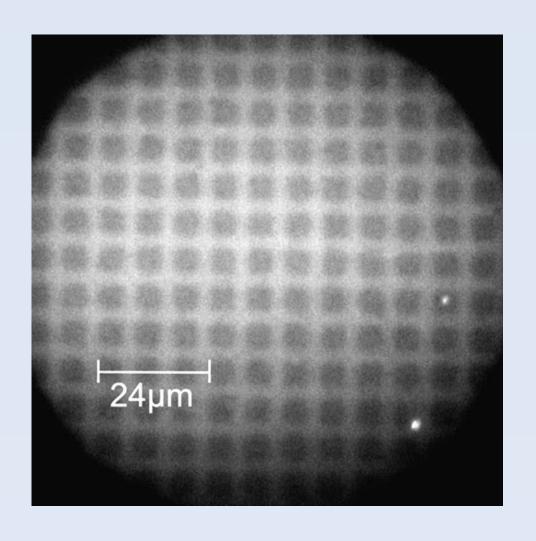
Vertical Distance 0.749 nm

XPS

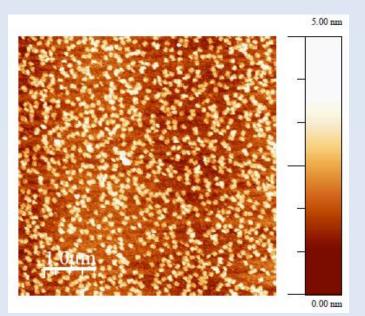


Questions?

DNA Immobilization on APTES

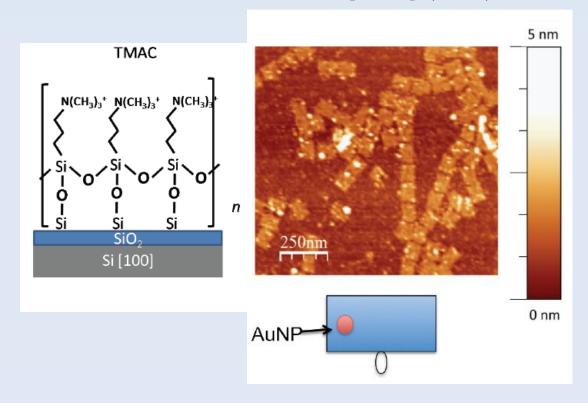


DNA Origami Immobilization onto APTES and TMAC



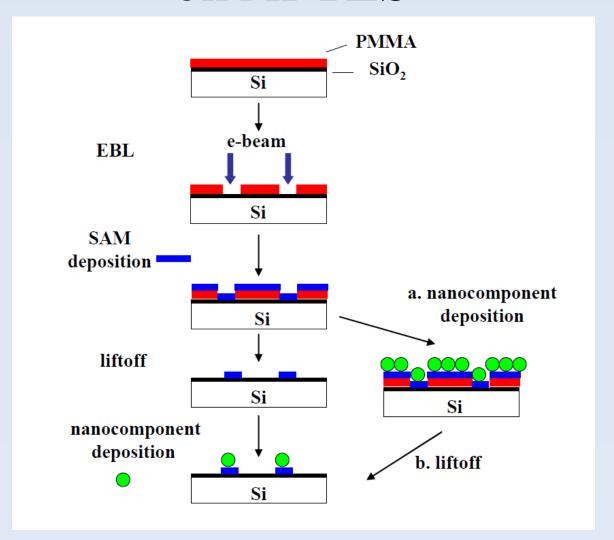
Goss, V. Adsorbing, Desorbing, Jamming, and Burning DNA Origami (2012)

Kim, K. Self-aligned DNA Oligomer and the Deposition of DNA Oligomers on EBL Patterned Cationic SAMs on SiO₂/Si [1001] (2012)



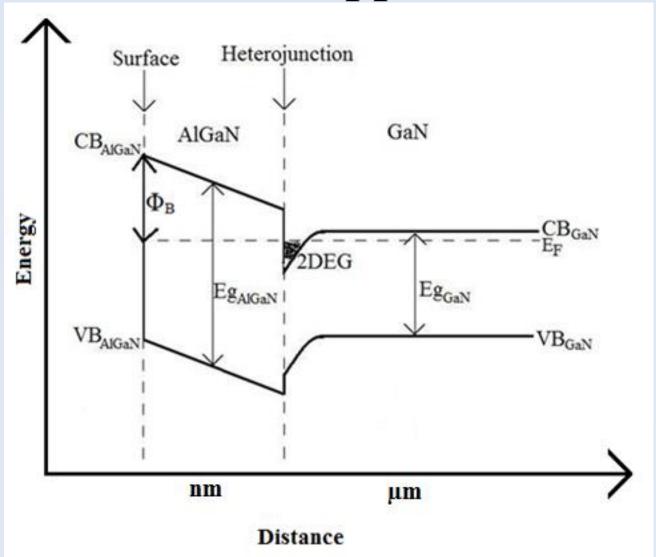
TMAC - Trimethyl[(trimethoxysilyl)propyl]ammonium chloride

Patterned DNA Origami Immobilization on APTES



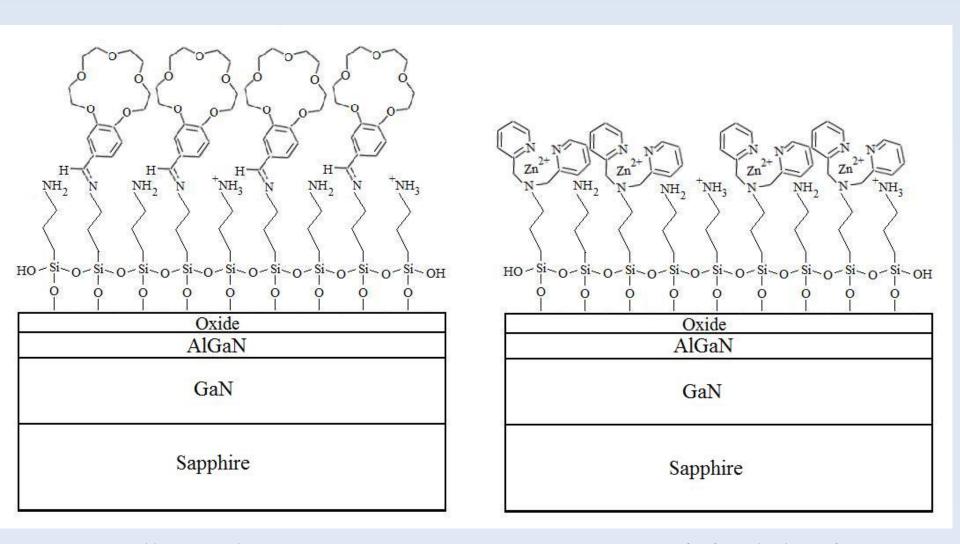
Gao, B. *PATTERNING BIOMOLECULES AT SUB-30 NM RESOLUTION BY ELECTRON BEAM LITHOGRAPHY* (2009)

HEMT Structures for Sensor Applications



HEMT High
Electron
Mobility
Transistor

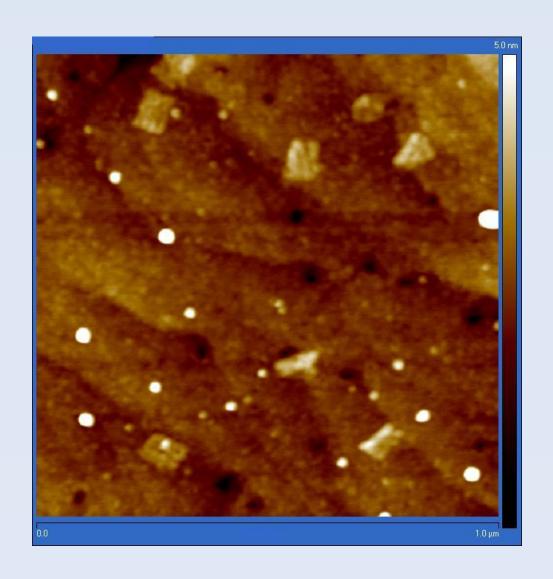
Ion Sensing SAM's on HEMT's



Formylbenzyl-15-crown-5

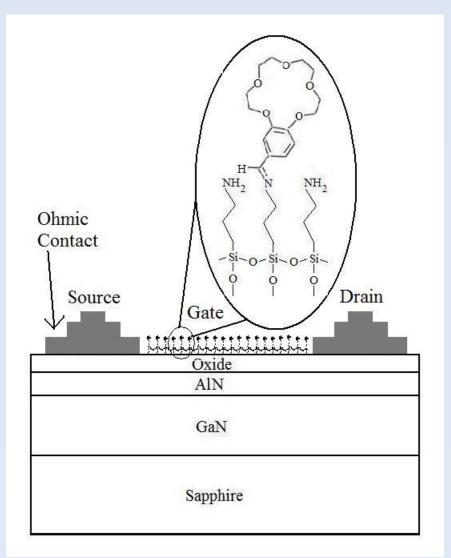
DPA - Dipicolylamine

DNA Origami on DPA-Zn-APTES

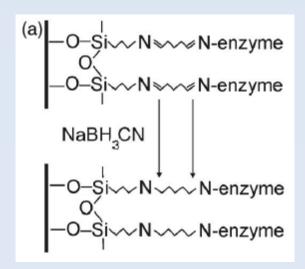


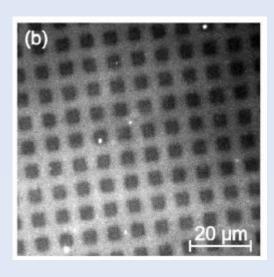
Functionalized Device (HEMT) Structure

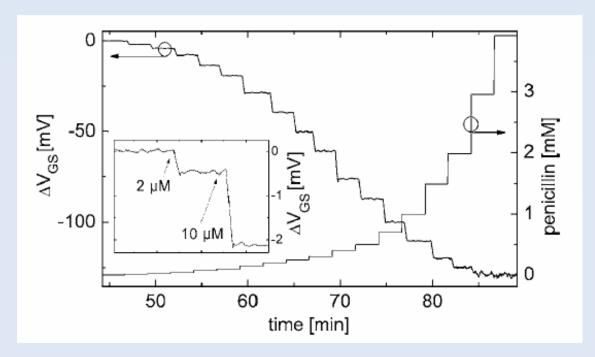
- Deposit metal Ohmic contacts on surface for source and drain
- APTES functionalization as gate region
- APTES modification w. crowns or DPA's
- Expose to solutions of target ions
- Measure sensor function



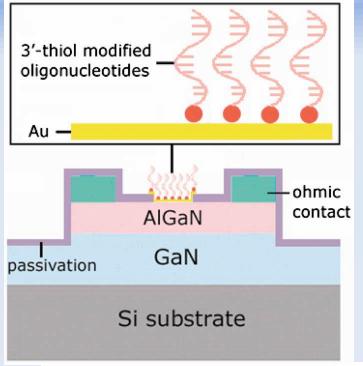
Enzyme Activity Sensor



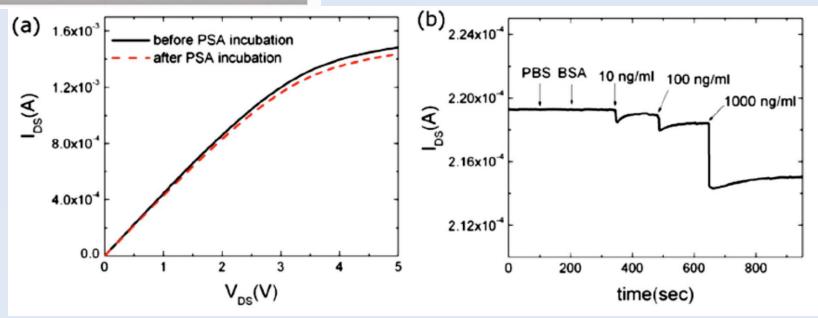




Baur et. al, Appl. Phys. Lett. 87, 183901 (2005)

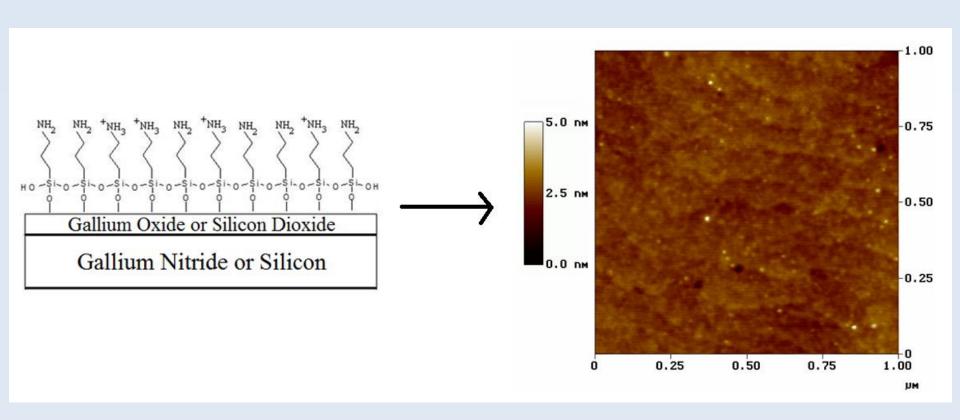


Functioning Sensor with another SAM/Surface Combination



Kang et. al. J. Appl. Phys. 104, 031101 (2008)

Conclusions



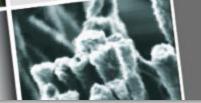
Acknowledgements

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 - Dr. Valerie Goss
 - Dr. Kyoung Nan Kim
- Dr. Huili Grace Xing (University of Notre Dame,
 - Dept. of Electrical Engineering)
- The University of Notre Dame
 - The non-referenced research
 presented was performed at the University
 of Notre Dame, Dept. of Chemistry.



Questions?

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